

2.5V Drive Nch+Nch MOSFET

US6K1

●Structure

Silicon N-channel MOSFET

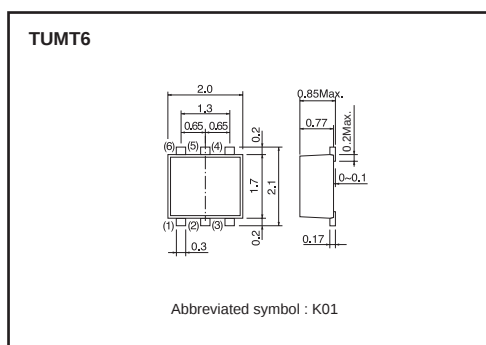
●Features

- 1) Low On-resistance.
- 2) Space savings small surface mount package (TUMT6).
- 3) Low voltage drive (2.5V drive).

●Applications

Switching

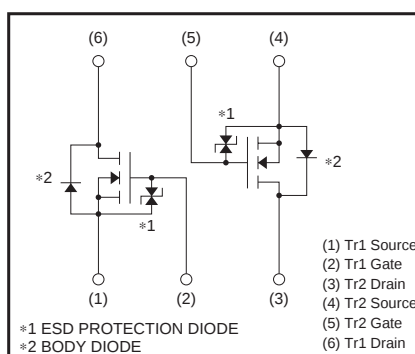
●Dimensions (Unit : mm)



●Packaging specifications

Type	Package	Taping
	Code	TR
	Basic ordering unit (pieces)	3000
US6K1		○

●Inner circuit



●Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		V_{DS}	30	V
Gate-source voltage		V_{GS}	12	V
Drain current	Continuous	I_D	± 1.5	A
	Pulsed	I_{DP} *1	± 6	A
Source current (Body diode)	Continuous	I_S	0.6	A
	Pulsed	I_{SP} *1	6	A
Total power dissipation		P_D *2	1.0	W / TOTAL
			0.7	W / ELEMENT
Channel temperature		T_{ch}	150	°C
Range of storage temperature		T_{stg}	-55 to +150	°C

*1 $P_w \leq 10 \mu s$, Duty cycle $\leq 1\%$

*2 Mounted on a ceramic board

●Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	$R_{th(ch-a)}$ *	125	°C/W / TOTAL
		179	°C/W / ELEMENT

* Mounted on a ceramic board

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I_{GSS}	–	–	10	μA	$V_{GS}=12V, V_{DS}=0V$
Drain-source breakdown voltage	$V_{(BR) DSS}$	30	–	–	V	$I_D=1mA, V_{GS}=0V$
Zero gate voltage drain current	I_{DSS}	–	–	1	μA	$V_{DS}=30V, V_{GS}=0V$
Gate threshold voltage	$V_{GS(th)}$	0.5	–	1.5	V	$V_{DS}=10V, I_D=1mA$
Static drain-source on-state resistance	$R_{DS(on)}^*$	–	170	240	$m\Omega$	$I_D=1.5A, V_{GS}=4.5V$
		–	180	250	$m\Omega$	$I_D=1.5A, V_{GS}=4.0V$
		–	240	340	$m\Omega$	$I_D=1.5A, V_{GS}=2.5V$
Forward transfer admittance	$ Y_{fs} ^*$	1.5	–	–	S	$V_{DS}=10V, I_D=1.5A$
Input capacitance	C_{iss}	–	80	–	pF	$V_{DS}=10V$
Output capacitance	C_{oss}	–	13	–	pF	$V_{GS}=0V$
Reverse transfer capacitance	C_{rss}	–	12	–	pF	$f=1MHz$
Turn-on delay time	$t_{d(on)}^*$	–	7	–	ns	$V_{DD}=15V$
Rise time	t_r^*	–	9	–	ns	$I_D=0.75A$
Turn-off delay time	$t_{d(off)}^*$	–	15	–	ns	$V_{GS}=4.5V$
Fall time	t_f^*	–	6	–	ns	$R_L=20\Omega$
Total gate charge	Q_g^*	–	1.6	2.2	nC	$V_{DD}=15V$
Gate-source charge	Q_{gs}^*	–	0.5	–	nC	$V_{GS}=4.5V$
Gate-drain charge	Q_{gd}^*	–	0.3	–	nC	$I_D=1.5A$

*Pulsed

●Body diode characteristics (Source-drain) (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V_{SD}	–	–	1.2	V	$I_S=0.6A, V_{GS}=0V$

●Electrical characteristics curves

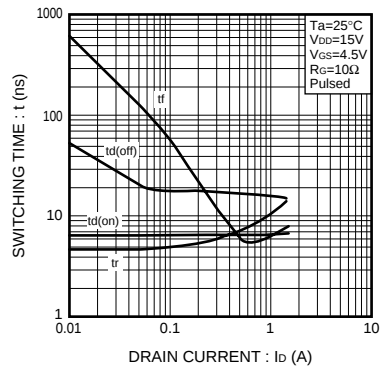


Fig.1 Switching Characteristics

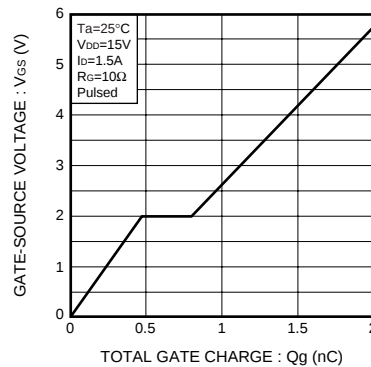


Fig.2 Dynamic Input Characteristics

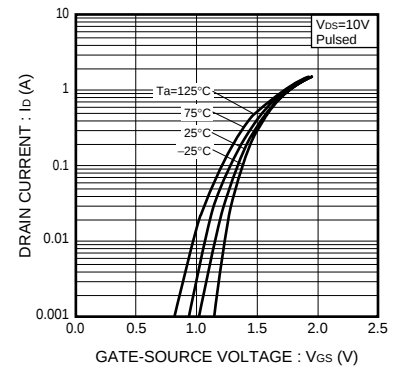
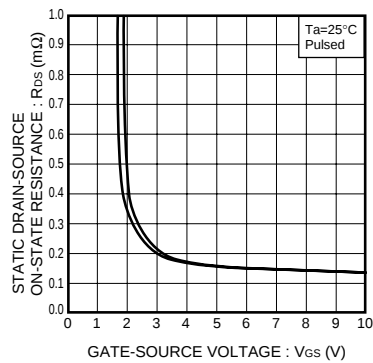
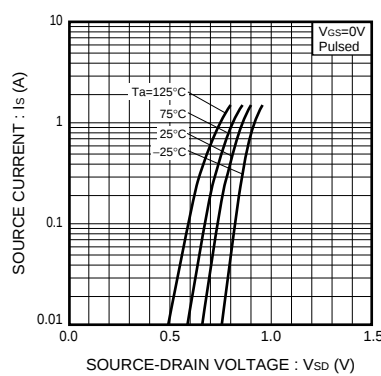
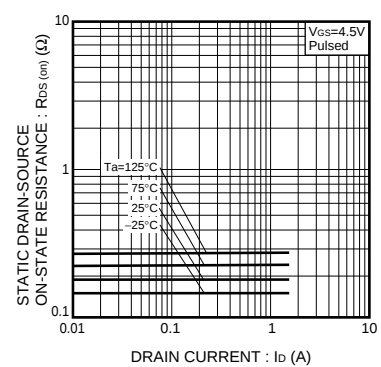
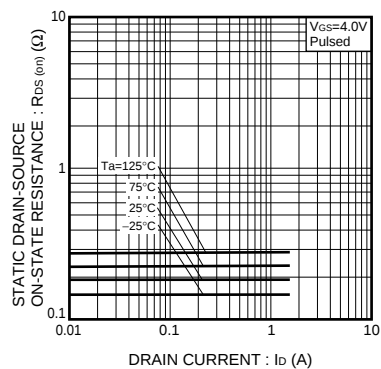
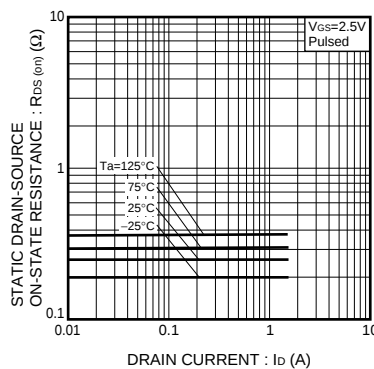
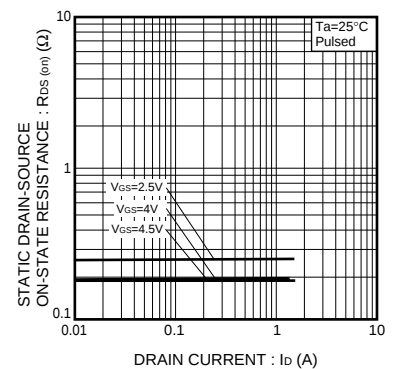


Fig.3 Typical Transfer Characteristics

Fig.4 Static Drain-Source
On-State Resistance vs.
Gate source VoltageFig.5 Source Current vs.
Source-Drain VoltageFig.6 Static Drain-Source
On-State Resistance
vs. Drain Current (I)Fig.7 Static Drain-Source
On-State Resistance
vs. Drain Current (II)Fig.8 Static Drain-Source
On-State Resistance
vs. Drain Current (III)Fig.9 Static Drain-Source
On-State Resistance
vs. Drain Current (IV)

Notes

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